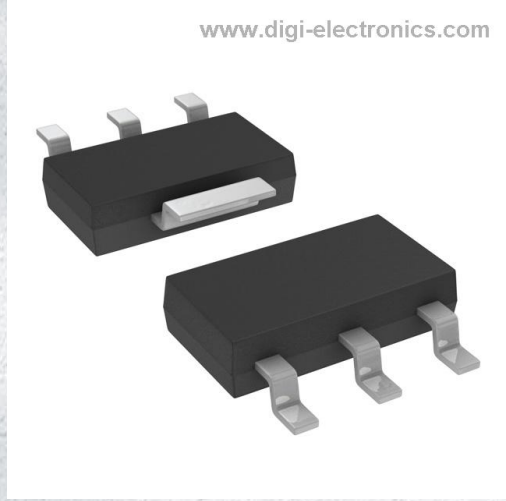
BSP16T1 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	BSP16T1-DG
Manufacturer	onsemi
Manufacturer Product Number	BSP16T1
Description	TRANS PNP 300V 0.1A SOT223
Detailed Description	Bipolar (BJT) Transistor PNP 300 V 100 mA 15MHz 1 .5 W Surface Mount SOT-223 (TO-261)

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BSP16T1	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
300 V	2V @ 5mA, 50mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
50µA	30 @ 50mA, 10V
Power - Max:	Frequency - Transition:
1.5 W	15MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223 (TO-261)
Base Product Number:	
BSP16	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0095	

onsemi

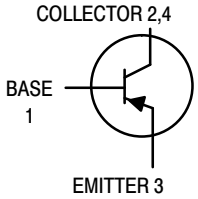
DATA SHEET
www.onsemi.com

High Voltage Transistors

PNP Silicon

BSP16T1G

PNP SILICON
HIGH VOLTAGE TRANSISTOR
SURFACE MOUNT



Features

- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	−300	Vdc
Collector-Base Voltage	V_{CBO}	−350	Vdc
Emitter-Base Voltage	V_{EBO}	−6.0	Vdc
Collector Current	I_C	−100	mAdc
Total Device Dissipation @ T_A = 25°C (Note 1)	P_D	1.5	W
Storage Temperature Range	P_D	−65 to +150	°C
Junction Temperature	T_J	150	°C

THERMAL CHARACTERISTICS

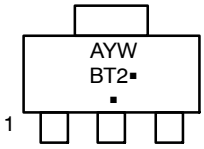
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	83.3	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Device mounted on a glass epoxy printed circuit board 1.575 in x 1.575 in x 0.059 in; mounting pad for the collector lead min. 0.93 sq. in.

MARKING DIAGRAM

SOT−223
CASE 318E
STYLE 1



A = Assembly Location
Y = Year
W = Work Week
BT2 =Device Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
BSP16T1G	SOT−223 (Pb−Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BSP16T1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (I_C = −50 mAdc, I_B = 0, L = 25 mH)	$V_{(BR)CEO}$	−300	–	Vdc
Collector – Base Breakdown Voltage (I_C = −100 μAdc, I_E = 0)	$V_{(BR)CBO}$	−300	–	Vdc
Collector−Emitter Cutoff Current (V_{CE} = −250 Vdc, I_B = 0)	I_{CES}	–	−50	μAdc
Collector−Base Cutoff Current (V_{CB} = −280 Vdc, I_E = 0)	I_{CBO}	–	−1.0	μAdc
Emitter−Base Cutoff Current (V_{EB} = −6.0 Vdc, I_C = 0)	I_{EBO}	–	−20	μAdc
ON CHARACTERISTICS				
DC Current Gain (V_{CE} = − 10 Vdc, I_C = −50 mAdc)	h_{FE}	30	120	–
Collector-Emitter Saturation Voltage (I_C = − 50 mAdc, I_B = − 5.0 mAdc)	$V_{CE(sat)}$	–	− 2.0	Vdc
DYNAMIC CHARACTERISTICS				
Current Gain − Bandwidth Product (V_{CE} = − 10 Vdc, I_C = −10 mAdc, f = 30 MHz)	f_T	15	–	MHz
Collector−Base Capacitance (V_{CB} = − 10 Vdc, I_E = 0, f = 1.0 MHz)	C_{obo}	–	15	pF

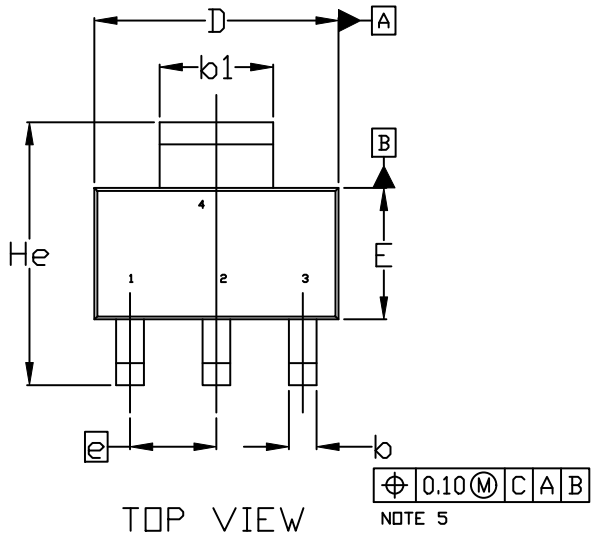
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

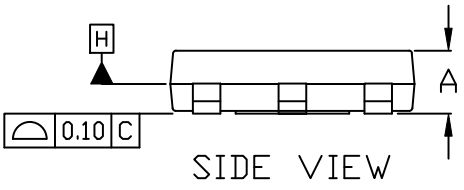
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

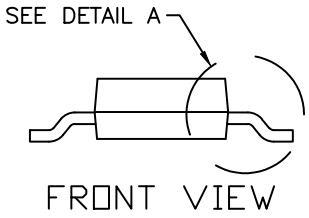
SCALE 1:1

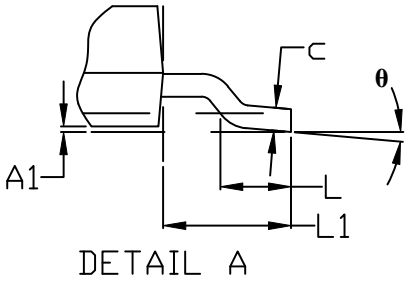
SOT−223 (TO−261)
CASE 318E−04
ISSUE R

DATE 02 OCT 2018



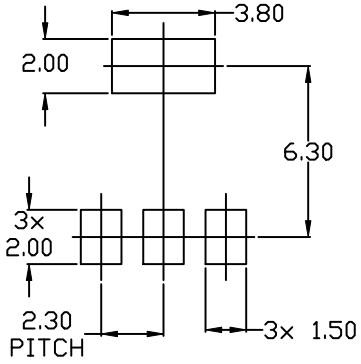






NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
4. DATUMS A AND B ARE DETERMINED AT DATUM H.
5. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS b AND b1.

	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
A	1.50	1.63	1.75
A1	0.02	0.06	0.10
b	0.60	0.75	0.89
b1	2.90	3.06	3.20
c	0.24	0.29	0.35
D	6.30	6.50	6.70
E	3.30	3.50	3.70
e	2.30 BSC		
L	0.20	---	---
L1	1.50	1.75	2.00
He	6.70	7.00	7.30
θ	0°	---	10°



RECOMMENDED MOUNTING FOOTPRINT

DOCUMENT NUMBER:	**98ASB42680B**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**SOT−223 (TO−261)**	**PAGE 1 OF 2**

SOT−223 (TO−261)
CASE 318E−04
ISSUE R

DATE 02 OCT 2018

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. CATHODE
3. NC
4. CATHODE

STYLE 3:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

STYLE 4:
PIN 1. SOURCE
2. DRAIN
3. GATE
4. DRAIN

STYLE 5:
PIN 1. DRAIN
2. GATE
3. SOURCE
4. GATE

STYLE 6:
PIN 1. RETURN
2. INPUT
3. OUTPUT
4. INPUT

STYLE 7:
PIN 1. ANODE 1
2. CATHODE
3. ANODE 2
4. CATHODE

STYLE 8:
CANCELLED

STYLE 9:
PIN 1. INPUT
2. GROUND
3. LOGIC
4. GROUND

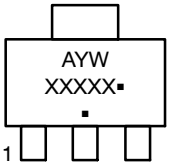
STYLE 10:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE

STYLE 11:
PIN 1. MT 1
2. MT 2
3. GATE
4. MT 2

STYLE 12:
PIN 1. INPUT
2. OUTPUT
3. NC
4. OUTPUT

STYLE 13:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

GENERIC MARKING DIAGRAM*



A = Assembly Location
Y = Year
W = Work Week
XXXXX = Specific Device Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**SOT−223 (TO−261)**	**PAGE 2 OF 2**

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TECHNICAL PUBLICATIONS:
Technical Library: www.onsemi.com/design/resources/technical−documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support
For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

OUR CERTIFICATE

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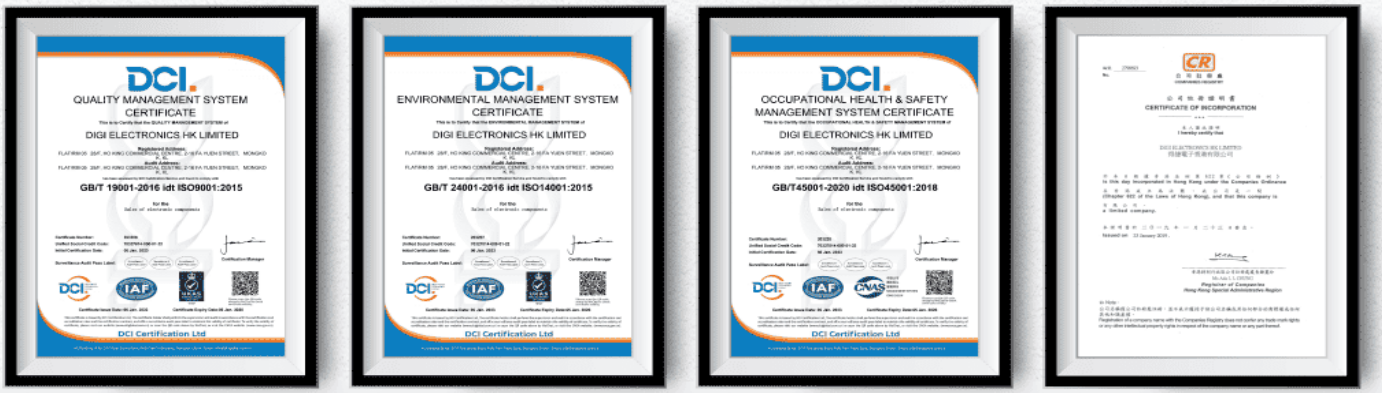

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